

# Silicon Tuning Diode

This device is designed for FM tuning, general frequency control and tuning, or any top-of-the-line application requiring back-to-back diode configurations for minimum signal distortion and detuning.

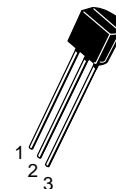
- High Figure of Merit —  $Q = 140$  (Typ) @  $V_R = 3.0$  Vdc,  $f = 100$  MHz
- Guaranteed Capacitance Range  
37–42 pF @  $V_R = 3.0$  Vdc (MV104)
- Dual Diodes – Save Space and Reduce Cost
- Monolithic Chip Provides Near Perfect Matching – Guaranteed  $\pm 1.0\%$  (Max) Over Specified Tuning Range

## MAXIMUM RATINGS (EACH DIODE)

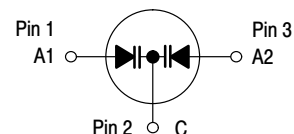
| Rating  | Symbol           | Value       | Unit                       |
|---|------------------|-------------|----------------------------|
| Reverse Voltage   | $V_R$            | 32          | Vdc                        |
| Forward Current   | $I_F$            | 200         | mAdc                       |
| Total Power Dissipation @ $T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | $P_D$            | 280<br>2.8  | mW<br>mW/ $^\circ\text{C}$ |
| Junction Temperature  | $T_J$            | +125        | $^\circ\text{C}$           |
| Storage Temperature Range   | $T_{\text{stg}}$ | –55 to +150 | $^\circ\text{C}$           |

# MV104

**DUAL  
VOLTAGE VARIABLE  
CAPACITANCE DIODE**



CASE 29–11, STYLE 15  
TO–92 (TO–226AA)



## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted) (EACH DIODE)

| Characteristic   | Symbol      | Min    | Typ    | Max       | Unit                  |
|--|-------------|--------|--------|-----------|-----------------------|
| Reverse Breakdown Voltage<br>( $I_R = 10 \mu\text{Adc}$ )  | $V_{(BR)R}$ | 32     | —      | —         | Vdc                   |
| Reverse Voltage Leakage Current $T_A = 25^\circ\text{C}$<br>( $V_R = 30$ Vdc) $T_A = 60^\circ\text{C}$ | $I_R$       | —<br>— | —<br>— | 50<br>500 | nAdc                  |
| Diode Capacitance Temperature Coefficient<br>( $V_R = 4.0$ Vdc, $f = 1.0$ MHz)                         | $TC_C$      | —      | 280    | —         | ppm/ $^\circ\text{C}$ |

|        | $C_T$ , Diode Capacitance<br>$V_R = 3.0$ Vdc, $f = 1.0$ MHz<br>pF |     | $Q$ , Figure of Merit<br>$V_R = 3.0$ Vdc<br>$f = 100$ MHz |     | $C_R$ , Capacitance Ratio<br>$C_3/C_{30}$<br>$f = 1.0$ MHz |     |
|--------|---|-----|---|-----|--|-----|
| Device | Min   | Max | Min   | Typ | Min  | Max |
| MV104  | 37  | 42  | 100   | 140 | 2.5  | 2.8 |

TYPICAL CHARACTERISTICS (Each Diode)

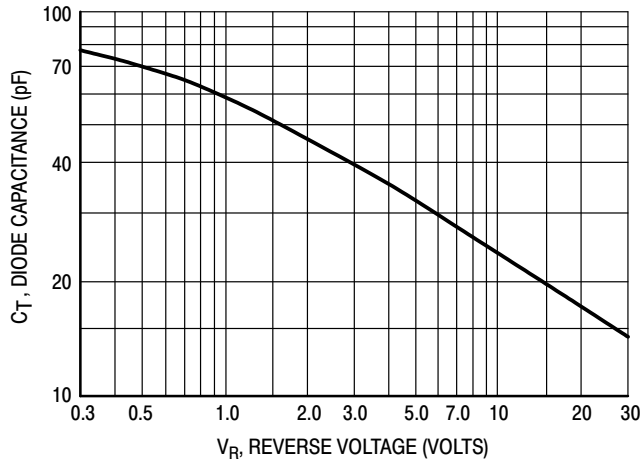


Figure 1. Diode Capacitance (Each Diode)

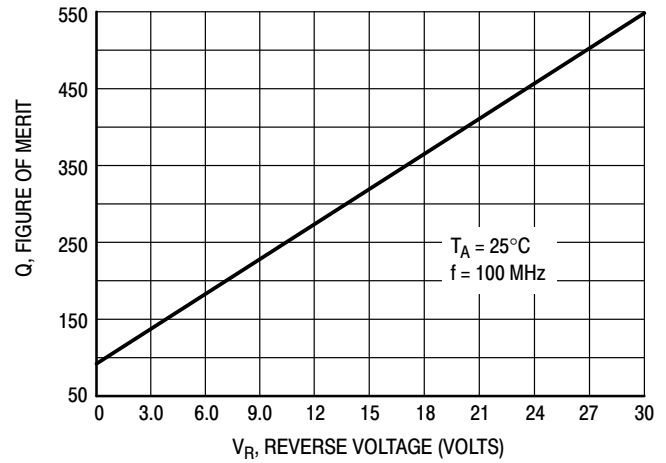


Figure 2. Figure of Merit versus Voltage

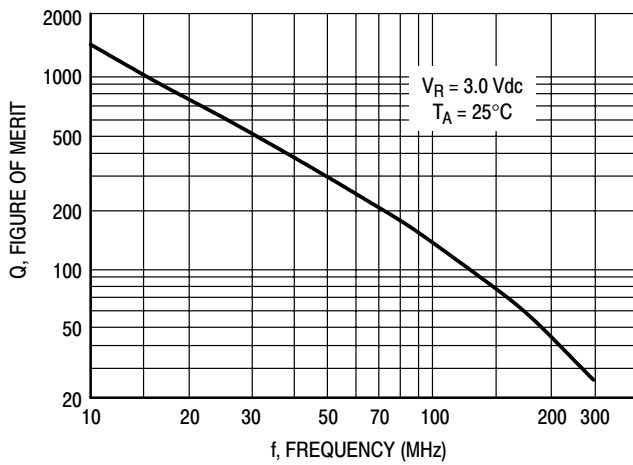


Figure 3. Figure of Merit versus Frequency

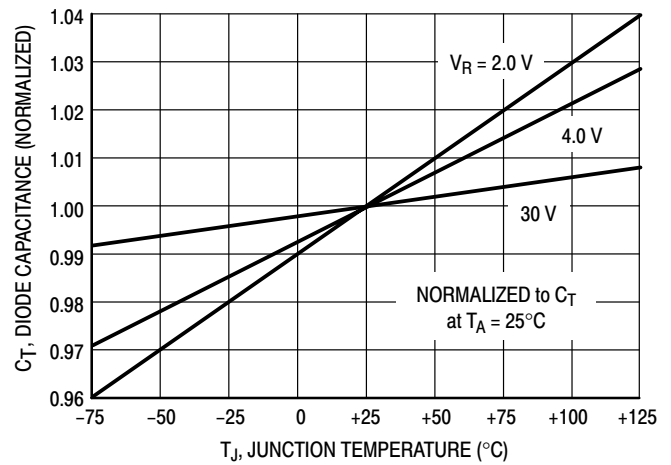


Figure 4. Diode Capacitance versus Temperature

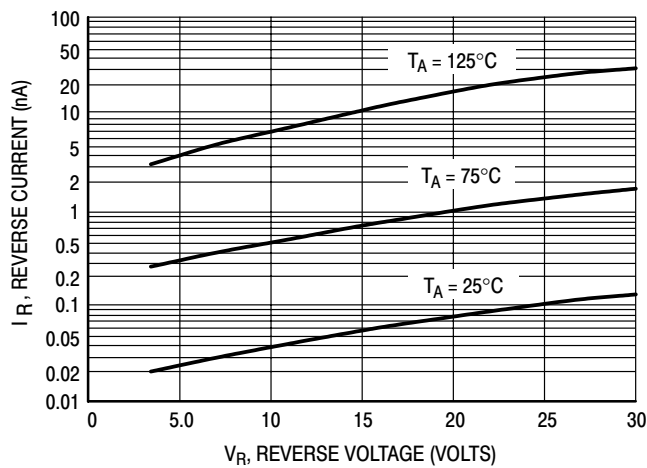
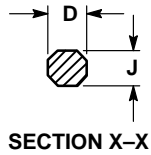
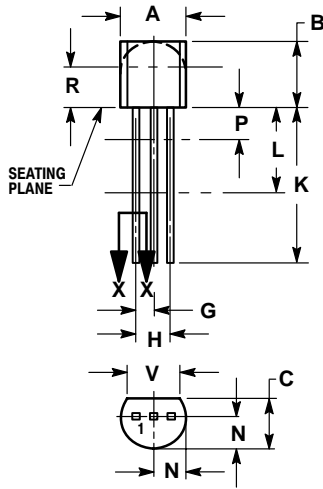


Figure 5. Reverse Current versus Reverse Voltage

# MV104

## PACKAGE DIMENSIONS

### TO-92 (TO-226AA) CASE 29-11 ISSUE AL




YLE 15:  
PIN 1. ANODE 1  
2. CATHODE  
3. ANODE 2

#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

| DIM | INCHES |       | MILLIMETERS |       |
|-----|--------|-------|-------------|-------|
|     | MIN    | MAX   | MIN         | MAX   |
| A   | 0.175  | 0.205 | 4.45        | 5.20  |
| B   | 0.170  | 0.210 | 4.32        | 5.33  |
| C   | 0.125  | 0.165 | 3.18        | 4.19  |
| D   | 0.016  | 0.021 | 0.407       | 0.533 |
| E   | 0.045  | 0.055 | 1.15        | 1.39  |
| F   | 0.095  | 0.105 | 2.42        | 2.66  |
| G   | 0.015  | 0.020 | 0.39        | 0.50  |
| H   | 0.500  | ---   | 12.70       | ---   |
| I   | 0.250  | ---   | 6.35        | ---   |
| J   | 0.080  | 0.105 | 2.04        | 2.66  |
| K   | ---    | 0.100 | ---         | 2.54  |
| L   | 0.115  | ---   | 2.93        | ---   |
| M   | 0.135  | ---   | 3.43        | ---   |

**ON Semiconductor** and  are trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer.

## PUBLICATION ORDERING INFORMATION

### NORTH AMERICA Literature Fulfillment:

Literature Distribution Center for ON Semiconductor  
P.O. Box 5163, Denver, Colorado 80217 USA  
**Phone:** 303-675-2175 or 800-344-3860 Toll Free USA/Canada  
**Fax:** 303-675-2176 or 800-344-3867 Toll Free USA/Canada  
**Email:** ONlit@hibbertco.com  
Fax Response Line: 303-675-2167 or 800-344-3810 Toll Free USA/Canada

**N. American Technical Support:** 800-282-9855 Toll Free USA/Canada

**EUROPE:** LDC for ON Semiconductor – European Support

**German Phone:** (+1) 303-308-7140 (Mon-Fri 2:30pm to 7:00pm CET)  
**Email:** ONlit-german@hibbertco.com

**French Phone:** (+1) 303-308-7141 (Mon-Fri 2:00pm to 7:00pm CET)  
**Email:** ONlit-french@hibbertco.com

**English Phone:** (+1) 303-308-7142 (Mon-Fri 12:00pm to 5:00pm GMT)  
**Email:** ONlit@hibbertco.com

**EUROPEAN TOLL-FREE ACCESS\*: 00-800-4422-3781**

\*Available from Germany, France, Italy, UK, Ireland

### CENTRAL/SOUTH AMERICA:

**Spanish Phone:** 303-308-7143 (Mon-Fri 8:00am to 5:00pm MST)  
**Email:** ONlit-spanish@hibbertco.com

**Toll-Free from Mexico:** Dial 01-800-288-2872 for Access –  
then Dial 866-297-9322

**ASIA/PACIFIC:** LDC for ON Semiconductor – Asia Support

**Phone:** 1-303-675-2121 (Tue-Fri 9:00am to 1:00pm, Hong Kong Time)  
**Toll Free from Hong Kong & Singapore:**

**001-800-4422-3781**

**Email:** ONlit-asia@hibbertco.com

**JAPAN:** ON Semiconductor, Japan Customer Focus Center

4-32-1 Nishi-Gotanda, Shinagawa-ku, Tokyo, Japan 141-0031

**Phone:** 81-3-5740-2700

**Email:** r14525@onsemi.com

**ON Semiconductor Website:** <http://onsemi.com>

For additional information, please contact your local Sales Representative.

This datasheet has been download from:

[www.datasheetcatalog.com](http://www.datasheetcatalog.com)

Datasheets for electronics components.